

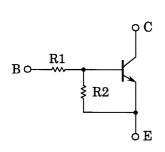
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## RN1701,RN1702,RN1703 RN1704,RN1705,RN1706

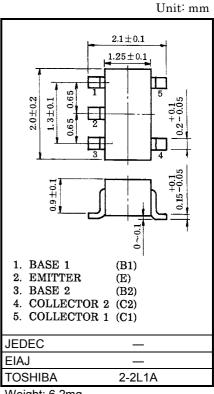
### Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in USV (ultra super mini type with 5 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2701~RN2706

### **Equivalent Circuit and Bias Resistor Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN1701	4.7	4.7
RN1702	10	10
RN1703	22	22
RN1704	47	47
RN1705	2.2	47
RN1706	4.7	47

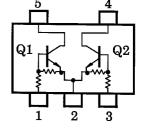


Weight: 6.2mg

### **Equivalent Circuit (Top View)**

### Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN1701~1706	V <sub>CBO</sub>	50	V	
Collector-emitter voltage	KN170131700	V <sub>CEO</sub>	50	V	
Emitter-base voltage	RN1701~1704	V	10	V	
	RN1705, 1706	V <sub>EBO</sub>	5		
Collector current		Ι <sub>c</sub>	100	mA	
Collector power dissipation	RN1701~1706	P <sub>c</sub> *	200	mW	
Junction temperature	KN1701~1700	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	



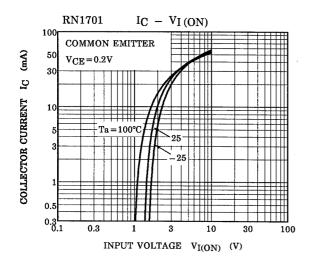
<sup>\*:</sup> Total rating

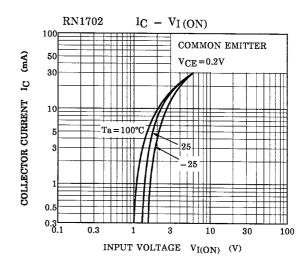


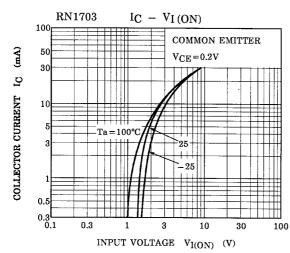
# Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

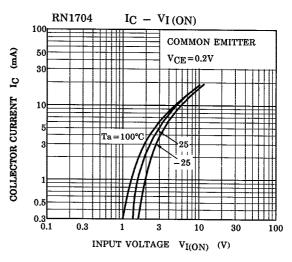
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	DN14704 4700	I <sub>CBO</sub>	_	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	nA
	RN1701~1706		_	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	_	_	500	
	RN1701		_	V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	mA
Emitter cut-off current	RN1702	I <sub>EBO</sub>	_		0.38	_	0.71	
	RN1703		_		0.17	_	0.33	
	RN1704		_		0.082	_	0.15	
	RN1705		_	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145	
	RN1706		_		0.074	_	0.138	
	RN1701		_		30	_	_	
	RN1702		_		50	_	_	
	RN1703		_		70	_	_	
DC current gain	RN1704	h <sub>FE</sub>	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	80	_	_	
	RN1705		_		80	_	_	
	RN1706	-	_		80	_	_	
Collector-emitter saturation voltage	RN1701~1706	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
Input voltage (ON)	RN1701	V <sub>I</sub> (ON)	_	- V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.1	_	2.0	V
	RN1702		_		1.2	_	2.4	
	RN1703		_		1.3	_	3.0	
	RN1704		_		1.5	_	5.0	
	RN1705		_		0.6	_	1.1	
	RN1706		_		0.7	_	1.3	
	RN1701~1704	V <sub>I (OFF)</sub>	_	- V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	V
Input voltage (OFF)	RN1705, 1706		_		0.5	_	0.8	
Translation frequency	RN1701~1706	f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector output capacitance	RN1701~1706	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	_	3	6	pF
Input resistor	RN1701	R1	_	_	3.29	4.7	6.11	kΩ
	RN1702		_		7	10	13	
	RN1703		_		15.4	22	28.6	
	RN1704		_		32.9	47	61.1	
	RN1705		_		1.54	2.2	2.86	
	RN1706		_		3.29	4.7	6.11	
Resistor ratio	RN1701~1705	R1/R2	_	_	0.9	1.0	1.1	_
	RN1705		_		0.0421	0.0468	0.0515	
	RN1706		_		0.09	0.1	0.11	

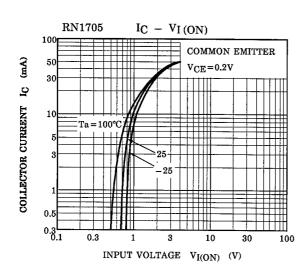
### (Q1, Q2 Common)

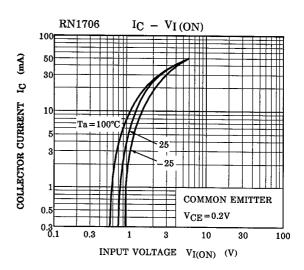






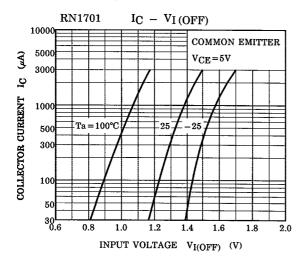


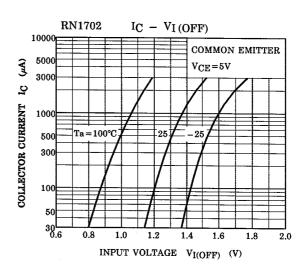


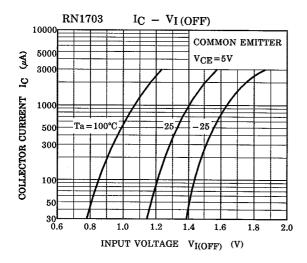


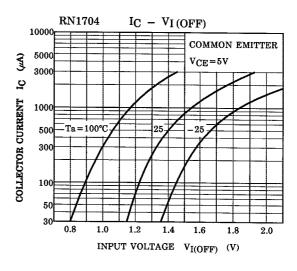
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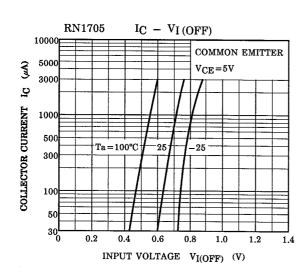
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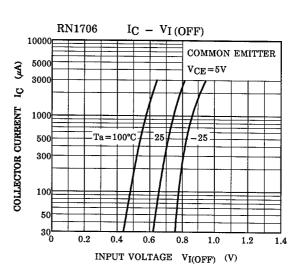




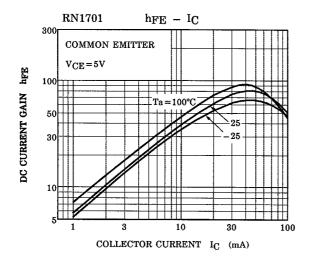


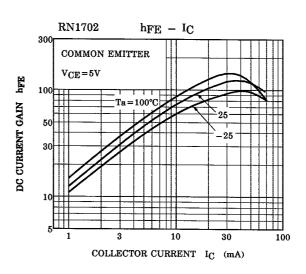


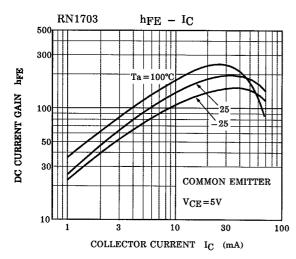


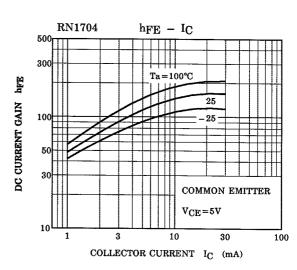


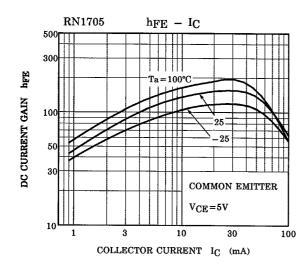
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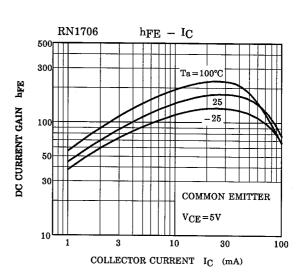












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Type Name	Marking
RN1701	Type Name  X A
RN1702	Type Name  X B
RN1703	Type Name  X C
RN1704	Type Name  X D
RN1705	Type Name  X E
RN1706	Type Name  X F

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